



IP4856CX25/C

SD 3.0-compliant memory card integrated dual level translator with EMI filter and ESD protection

Rev. 3 — 13 December 2019

Product data sheet

1. General description

The device is an SD 3.0-compliant 6-bit bidirectional dual voltage level translator. It is designed to interface between a memory card operating at 1.8 V or 2.9 V signal levels and a host with a fixed nominal supply voltage of 1.7 V to 3.6 V. The device supports SD 3.0, SDR104, SDR50, DDR50, SDR25, SDR12 and SD 2.0 high-speed (50 MHz) and default-speed (25 MHz) modes. The device has an integrated voltage selectable low dropout regulator to supply the card-side I/Os, built-in EMI filters and robust ESD protections (IEC 61000-4-2, level 4).

2. Features and benefits

- Supports up to 208 MHz clock rate
- Feedback channel for clock synchronization
- SD 3.0 specification-compliant voltage translation to support SDR104, SDR50, DDR50, SDR25, SDR12, high-speed and default-speed modes
- 100 mA low dropout voltage regulator to supply the card-side I/Os
- Low power consumption by push-pull output stage with break-before-make architecture
- Integrated pull-up and pull-down resistors: no external resistors required
- Integrated EMI filters suppress higher harmonics of digital I/Os
- Integrated 8 kV ESD protection according to IEC 61000-4-2, level 4 on card side
- Level shifting buffers keep ESD stress away from the host (zero-clamping concept)
- 25-ball WLCSP; pitch 0.4 mm

3. Applications

- Smartphone
- Mobile handsets
- Digital cameras
- Tablet PCs
- Laptop computers
- SD, MMC or microSD card readers

4. Ordering information

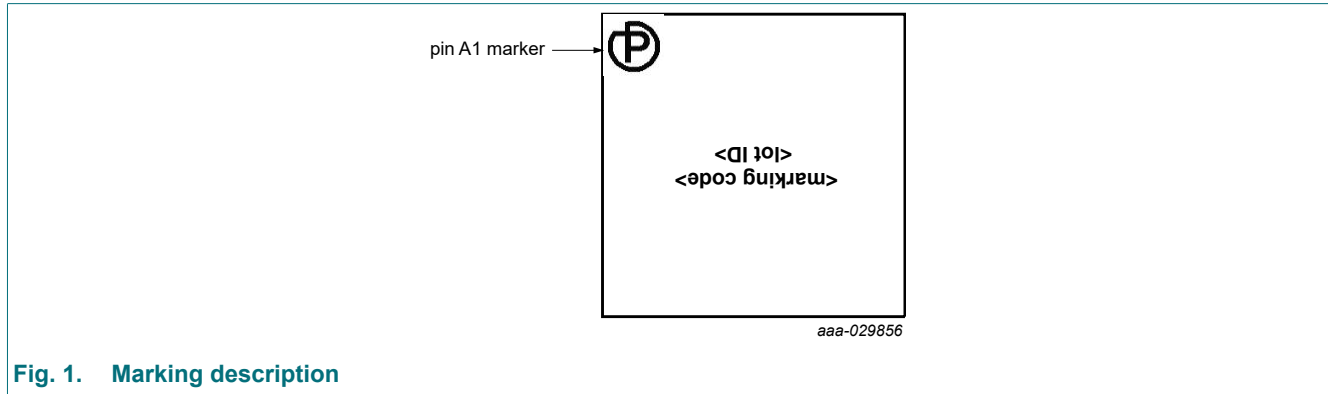
Table 1. Ordering information

Type number	Package	
	Name	Description
IP4856CX25/C	WLCSP25	wafer level chip-size package with back side coating; 25 bumps (5 x 5); typical size: 2.05 mm x 2.05 mm x 0.51 mm

5. Marking

Table 2. Marking code

Type number	Marking code
IP4856CX25/C	856



6. Block diagram

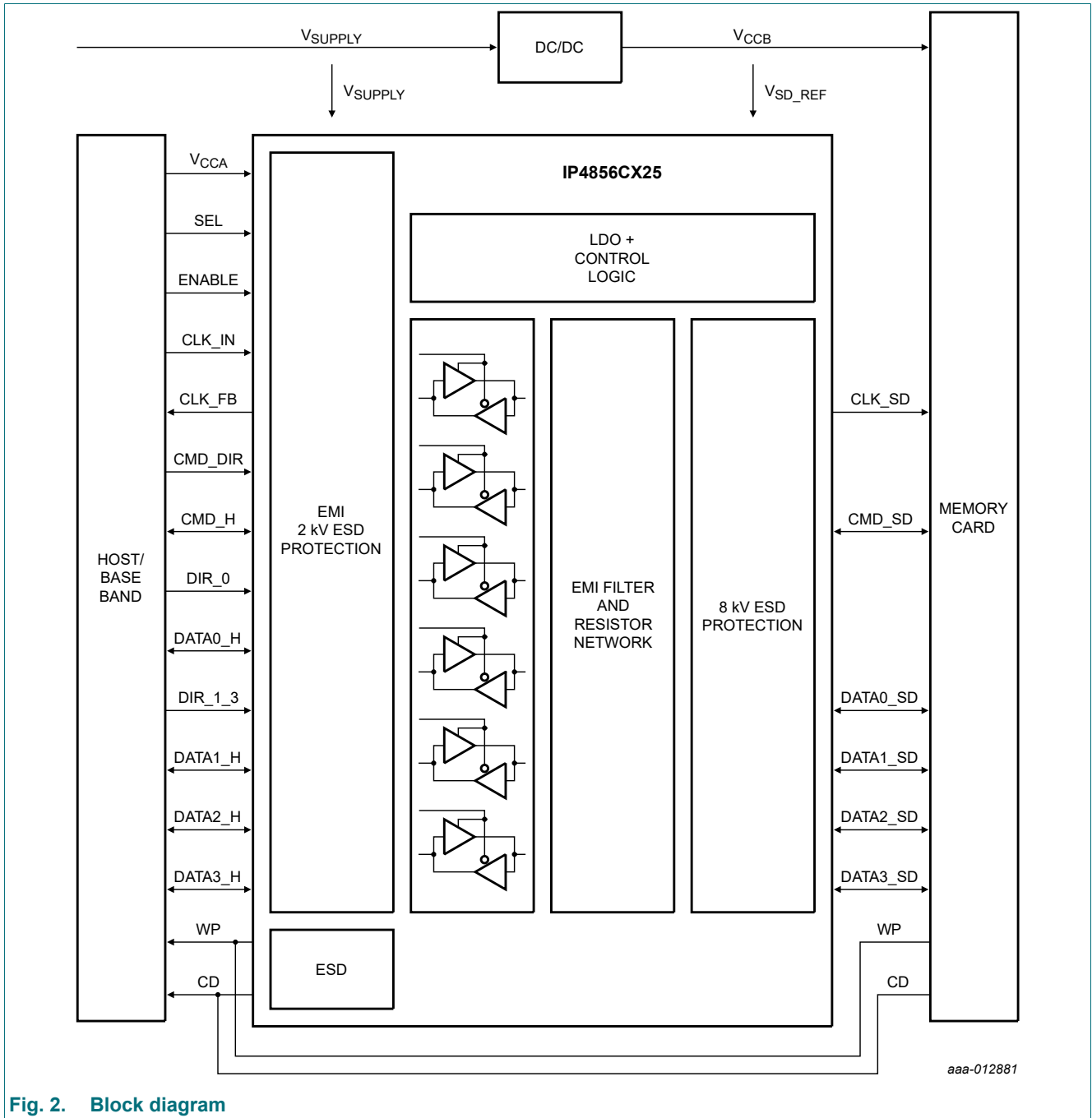


Fig. 2. Block diagram

7. Functional diagram

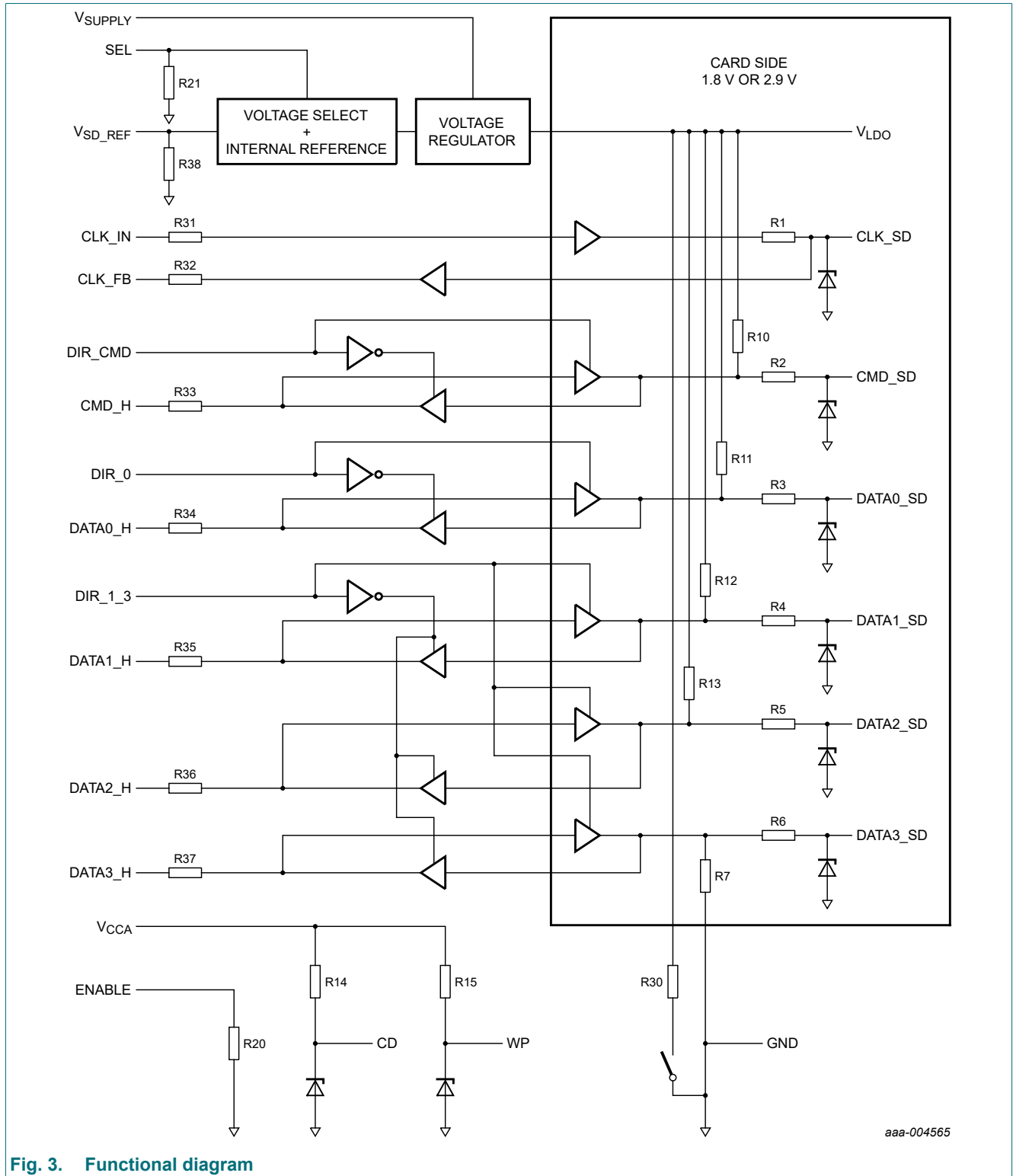


Fig. 3. Functional diagram

8. Pinning information

8.1. Pinning

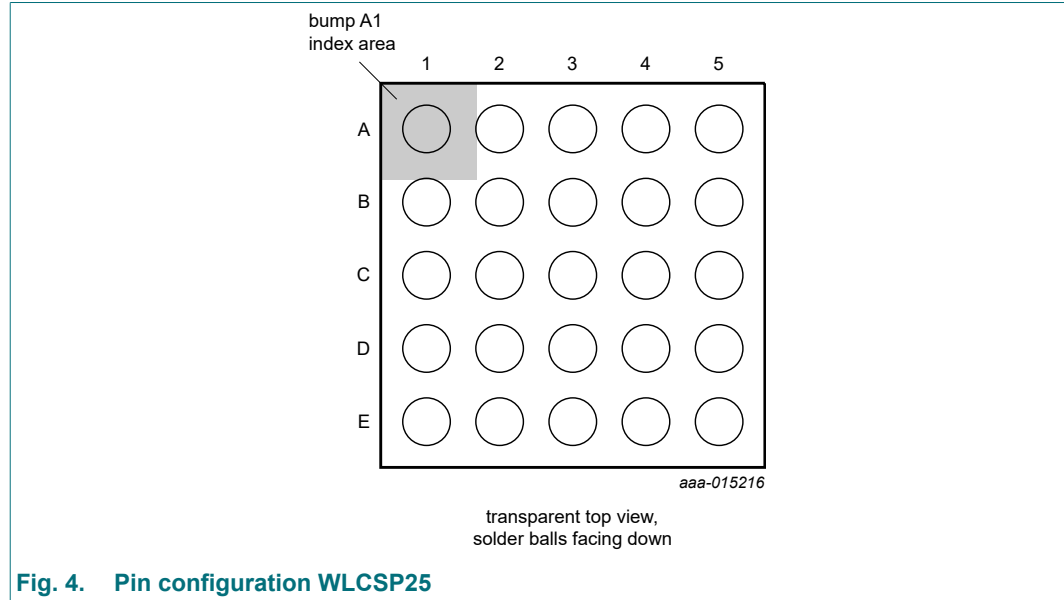


Fig. 4. Pin configuration WLCSP25

Table 3. Pin allocation table

Pin	Symbol	Pin	Symbol	Pin	Symbol	Pin	Symbol	Pin	Symbol
A1	DATA2_H	A2	DIR_CMD	A3	DIR_0	A4	V _{SUPPLY}	A5	DATA2_SD
B1	DATA3_H	B2	SEL	B3	V _{CCA}	B4	V _{LDO}	B5	DATA3_SD
C1	CLK_IN	C2	ENABLE	C3	GND	C4	V _{SD_REF}	C5	CLK_SD
D1	DATA0_H	D2	CMD_H	D3	CD	D4	CMD_SD	D5	DATA0_SD
E1	DATA1_H	E2	CLK_FB	E3	DIR_1_3	E4	WP	E5	DATA1_SD

8.2. Pin description

Table 4. Pin description

Symbol[1]	Pin	Type[2]	Description
DATA2_H	A1	I/O	data 2 input or output on host side
DIR_CMD	A2	I	direction control input for command
DIR_0	A3	I	direction control input for data 0
V _{SUPPLY}	A4	S	supply voltage (from battery or regulator)
DATA2_SD	A5	I/O	data 2 input or output on memory card side
DATA3_H	B1	I/O	data 3 input or output on host side
SEL	B2	I	card side I/O voltage level select
V _{CCA}	B3	S	supply voltage from host side
V _{LDO}	B4	O	internal supply decoupling
DATA3_SD	B5	I/O	data 3 input or output on memory card side
CLK_IN	C1	I	clock signal input on host side
ENABLE	C2	I	device enable input
GND	C3	S	supply ground

SD 3.0-compliant memory card integrated dual level translator with EMI filter and ESD protection

Symbol[1]	Pin	Type[2]	Description
V _{SD_REF}	C4	I	reference voltage for the internal voltage regulator
CLK_SD	C5	O	clock signal output on memory card side
DATA0_H	D1	I/O	data 0 input or output on host side
CMD_H	D2	I/O	command input or output on host side
CD	D3	O	card detect switch biasing output
CMD_SD	D4	I/O	command input or output on memory card side
DATA0_SD	D5	I/O	data 0 input or output on memory card side
DATA1_H	E1	I/O	data 1 input or output on host side
CLK_FB	E2	O	clock feedback output on host side
DIR_1_3	E3	I	direction control input for data 1, data 2, data 3
WP	E4	O	write protect switch biasing output
DATA1_SD	E5	I/O	data 1 input or output on memory card side

[1] The pin names relate particularly to SD memory cards, but also apply to microSD and MMC memory cards.

[2] I = input, O = output, I/O = input and output, S = power supply.

9. Functional description

9.1. Level translator

The bidirectional level translator shifts the data between the I/O supply levels of the host and the memory card. Dedicated direction control signals determine if a command and data signals are transferred from the memory card to the host (card read mode) or from the host to the memory card (card write mode). The voltage translator has to support several clock and data transfer rates at the signaling levels specified in the SD 3.0 standard specification.

Table 5. Supported modes

Bus speed mode	Signal level (V)	Clock rate (MHz)	Data rate (MB/s)
Default-speed	3.3	25	12.5
High-speed	3.3	50	25
SDR12	1.8	25	12.5
SDR25	1.8	50	25
SDR50	1.8	100	50
SDR104	1.8	208	104
DDR	1.8	50	50

9.2. Enable and direction control

The pin ENABLE enables/disables the internal Low DropOut (LDO) regulator and is used to put the host-side and card-side I/O drivers into high-ohmic (3-state) mode.

Table 6. I/O function control signal truth table

Control		Host side		Memory card side	
Pin	Level ^[1]	Pin	Function	Pin	Function
Pin ENABLE = HIGH and $V_{CCA} \geq 1.62$ V					
DIR_CMD	H	CMD_H	input	CMD_SD	output
	L	CMD_H	output	CMD_SD	input
DIR_0	H	DATA0_H	input	DATA0_SD	output
	L	DATA0_H	output	DATA0_SD	input
DIR_1_3	H	DATA1_H	input	DATA1_SD	output
		DATA2_H		DATA2_SD	
		DATA3_H		DATA3_SD	
	L	DATA1_H	output	DATA1_SD	input
		DATA2_H		DATA2_SD	
		DATA3_H		DATA3_SD	
-	-	CLK_IN	input	CLK_SD	output
-	-	CLK_FB	output	-	-
Pin ENABLE = LOW or $V_{CCA} \leq 0.8$ V					
DIR_CMD	X	CMD_H	high-ohmic	CMD_SD	high-ohmic
DIR_0	X	DATA0_H	high-ohmic	DATA0_SD	high-ohmic
DIR_1_3	X	DATA1_H	high-ohmic	DATA1_SD	high-ohmic
		DATA2_H		DATA2_SD	
		DATA3_H		DATA3_SD	
-	-	CLK_IN	input	CLK_SD	high-ohmic
-	-	CLK_IN	high-ohmic	-	-

[1] H = HIGH; L = LOW; X = don't care

9.3. Integrated voltage regulator

The low dropout voltage regulator delivers supply voltage for the voltage translators and the card-side input/output stages. It has to support 1.8 V and 3 V signaling modes as stipulated in the SD 3.0 specification. The switching time between the two output voltage modes is compliant with SD 3.0 specification. Depending on the signaling level at pin SEL, the regulator delivers 1.8 V (SEL = HIGH) or 2.9 V (SEL = LOW, $V_{SD_REF} < 1\text{ V}$). For card supply voltage, see [Section 9.4](#).

Table 7. SD card side voltage level control signal truth table

Input		Output		
SEL[1]	V_{SD_REF} [1]	V_{LDO}	Pin[2]	Function
H	X	1.8 V	DATA0_SD to DATA3_SD, CLK_SD	low supply voltage level (1.8 V typical)
L	< 1 V	2.9 V	DATA0_SD to DATA3_SD, CLK_SD	high supply voltage level (2.9 V typical)
	> 1.5 V	V_{SD_REF}	DATA0_SD to DATA3_SD, CLK_SD	supply voltage level based on V_{SD_REF}

[1] H = HIGH; L = LOW; X = don't care.

[2] Host-side pins are not influenced by SEL.

An external capacitor is needed between the regulator output pin V_{LDO} and ground for proper operation of the integrated voltage regulator. See [Table 9](#) for recommended capacitance and equivalent series resistance. It is recommended to place the capacitor close to the V_{LDO} pin and maintain short connections to both, to the V_{LDO} and to the ground.

9.4. Memory card voltage tracking (reference select)

The device can track the memory card supply via pin V_{SD_REF} . This allows achieving optimum interoperability by perfectly matching input/output levels between voltage translator and memory card in the 3 V signaling mode. Therefore, the voltage regulator aims to follow the reference voltage provided at input V_{SD_REF} directly. If tracking of the memory card supply is not desired, connect pin V_{SD_REF} to ground so the voltage regulator refers to an integrated voltage reference. For 1.8 V (SEL = HIGH) signaling, the voltage regulator is referred to the internal reference which is independent of the voltage at V_{SD_REF} .

9.5. Feedback clock channel

The clock is transmitted from the host to the memory card side. The voltage translator and the Printed-Circuit Board (PCB) tracks introduce some amount of delay. It reduces timing margin for data read back from memory card, especially at higher data rates. Therefore, a feedback path is provided to compensate the delay. The reasoning behind this approach is the fact that the clock is always delivered by the host, while the data in the timing critical read mode comes from the card.

9.6. EMI filter

All input/output driver stages are equipped with EMI filters to reduce interferences towards sensitive mobile communication.

9.7. ESD protection

The device has robust ESD protections on all memory card pins as well as on the V_{SD_REF} and V_{SUPPLY} pins. The architecture prevents any stress for the host: the voltage translator discharges any stress to supply ground.

Pins Write Protect (WP) and Card Detection (CD) might be pulled down by the memory card which has to be detected by the host. Both signals must be HIGH if no card is inserted. Therefore the pins are equipped with International Electrotechnical Commission (IEC) system-level ESD protections and pull-up resistors connected to the host supply V_{CCA} .

10. Limiting values

Table 8. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	supply voltage	4 ms transient; on pin V _{SUPPLY}	-0.5	4.6	V	
		4 ms transient; on pin V _{CCA}	-0.5	4.6	V	
V _I	input voltage	4 ms transient at I/O pins	-0.5	4.6	V	
P _{tot}	total power dissipation	T _{amb} = -40 °C to 85 °C	-	1000	mW	
T _{stg}	storage temperature		-55	150	°C	
T _{amb}	ambient temperature		-40	85	°C	
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2, level 4; all memory card-side pins, V _{SUPPLY} , V _{SD_REF} , WP and CD to ground; contact discharge	[1]	-8	8	kV
		IEC 61000-4-2, level 4; all memory card-side pins, V _{SUPPLY} , V _{SD_REF} , WP and CD to ground; air discharge	[1]	-15	15	kV
I _{IU(IO)}	input/output latch-up current	JESD78B: -0.5 x V _{CC} < V _I < 1.5 x V _{CC} ; T _j < 125 °C	-100	100	mA	

[1] All system level test are performed with the application-specific capacitors connected to the supply pins V_{SUPPLY}, V_{LDO} and V_{CCA}.

11. Recommended operating conditions

Table 9. Operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage	on pin V _{SUPPLY}	[1] 2.8	-	3.6	V
		on pin V _{CCA}	1.7	-	V _{SUPPLY}	V
V _I	input voltage	host side	[2] -0.3	-	V _{CCA} + 0.3	V
		memory card side	-0.3	-	V _{O(reg)} + 0.3	V
C _{ext}	external capacitance	recommended capacitor at pin V _{LDO}	-	1.0	-	μF
		recommended capacitor at pin V _{SUPPLY}	-	0.1	-	μF
		recommended capacitor at pin V _{CCA}	-	0.1	-	μF
ESR	equivalent series resistance	at pin V _{LDO}	0	-	50	mΩ

[1] By minimum value the device is still fully functional, but the voltage on pin V_{LDO} might drop below the recommended memory card supply voltage.

[2] The voltage must not exceed 3.6 V.

Table 10. Integrated resistors

T_{amb} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R _{pd}	pull-down resistance	R7	272	470	668	kΩ
		R30	70	100	130	Ω
		R20; R21; R38	200	350	500	kΩ
R _{pu}	pull-up resistance	R10	10.5	15	19.5	kΩ
		R11 to R13	49	70	91	kΩ
		R14 and R15	70	100	130	kΩ
R _s	series resistance	card side; R1 to R6	[1] 12	15	18	Ω
		host side; R31 to R37	[1] 18	22.5	27	Ω

[1] Guaranteed by design and characterization

12. Static characteristics

Table 11. Static characteristics

At recommended operating conditions; $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $85\text{ }^{\circ}\text{C}$; voltages are referenced to GND (ground = 0 V); $C_{ext} = 1\text{ }\mu\text{F}$ at pin V_{LDO} ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit	
Supply voltage regulator for card-side I/O pin: V_{LDO}							
$V_{O(\text{reg})}$	regulator output voltage	SEL = LOW; $V_{SD_REF} < 1\text{ V}$; $V_{SUPPLY} \geq 2.9\text{ V}$	2.7	2.9	3.3	V	
		SEL = LOW; $V_{SD_REF} < 1.5\text{ V}$; $V_{SUPPLY} \geq V_{SD_REF}$	$V_{SD_REF} - 0.15$	V_{SD_REF}	$V_{SD_REF} + 0.15$	V	
		SEL = HIGH; $V_{SUPPLY} \geq 2.5\text{ V}$	1.7	1.85	2.0	V	
$V_{do(\text{reg})}$	regulator dropout voltage	SEL = LOW; $V_{SUPPLY} \geq 2.9\text{ V}$; $I_O = 50\text{ mA}$	-	-	150	mV	
$I_{O(\text{reg})}$	regulator output current		-	-	100	mA	
Host-side input signals: CMD_H, DATA0_H to DATA3_H and CLK_IN							
V_{IH}	HIGH-level input voltage		$0.625 \times V_{CCA}$	-	$V_{CCA} + 0.3$	V	
V_{IL}	LOW-level input voltage		-0.3	-	$0.35 \times V_{CCA}$	V	
I_{LI}	input leakage current	$V_{CCA} = 1.8\text{ V}$; ENABLE = LOW	[2]	-	1.0	nA	
Host-side control signals							
V_{IH}	HIGH-level input voltage	SEL, ENABLE, DIR_0, DIR_1_3 and DIR_CMD	$0.625 \times V_{CCA}$	-	$V_{CCA} + 0.3$	V	
V_{IL}	LOW-level input voltage		-0.3	-	$0.35 \times V_{CCA}$	V	
V_{IH}	HIGH-level input voltage	V_{SD_REF}	1.5	-	3.63	V	
V_{IL}	LOW-level input voltage		-0.3	-	1.0	V	
Host-side output signals: CLK_FB, CMD_H and DATA0_H to DATA3_H							
V_{OH}	HIGH-level output voltage	$I_O = 2\text{ mA}$; $V_I = V_{IH}$ (card side)	$0.85 \times V_{CCA}$	-	-	V	
V_{OL}	LOW-level output voltage	$I_O = -2\text{ mA}$; $V_I = V_{IL}$ (card side)	-	-	$0.125 \times V_{CCA}$	V	
Card-side input signals: CMD_SD and DATA0_SD to DATA3_SD							
V_{IH}	HIGH-level input voltage	SEL = LOW (2.9 V interface)	$0.625 \times V_{O(\text{reg})}$	-	$V_{O(\text{reg})} + 0.3$	V	
		SEL = HIGH (1.8 V interface)	$0.625 \times V_{O(\text{reg})}$	-	$V_{O(\text{reg})} + 0.3$	V	
V_{IL}	LOW-level input voltage	SEL = LOW (2.9 V interface)	-0.3	-	$0.35 \times V_{O(\text{reg})}$	V	
		SEL = HIGH (1.8 V interface)	-0.3	-	$0.35 \times V_{O(\text{reg})}$	V	
Card-side output signal							
CMD_SD, DATA0_SD to DATA3_SD and CLK_SD							
V_{OH}	HIGH-level output voltage	$I_O = 4\text{ mA}$; $V_I = V_{IH}$ (host side); SEL = LOW (2.9 V interface)	$0.85 \times V_{O(\text{reg})}$	-	$V_{O(\text{reg})} + 0.3$	V	
		$I_O = 2\text{ mA}$; $V_I = V_{IH}$ (host side); SEL = HIGH (1.8 V interface)	$0.85 \times V_{O(\text{reg})}$	-	2.0	V	
V_{OL}	Low-level output voltage	$I_O = -4\text{ mA}$; $V_I = V_{IL}$ (host side); SEL = LOW (2.9 V interface)	-0.3	-	$0.125 \times V_{O(\text{reg})}$	V	
		$I_O = -2\text{ mA}$; $V_I = V_{IL}$ (host side); SEL = HIGH (1.8 V interface)	-0.3	-	$0.125 \times V_{O(\text{reg})}$	V	
Bus signal equivalent capacitance							
C_{ch}	channel capacitance	$V_I = 0\text{ V}$; $f_i = 1\text{ MHz}$; $V_{SUPPLY} = 3.5\text{ V}$; $V_{CCA} = 1.8\text{ V}$; host side	[3]	-	3.5	5	pF
		$V_I = 0\text{ V}$; $f_i = 1\text{ MHz}$; $V_{SUPPLY} = 3.5\text{ V}$; $V_{CCA} = 1.8\text{ V}$; card side	[3]	-	5	10	pF

SD 3.0-compliant memory card integrated dual level translator with EMI filter and ESD protection

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
Current consumption						
$I_{CC(stat)}$	static supply current	ENABLE = HIGH (active mode); all inputs = HIGH; DIR = LOW; SEL = LOW (2.9 V interface)	-	-	100	μA
		ENABLE = HIGH (active mode); all inputs = HIGH; DIR = LOW; SEL = HIGH (1.8 V interface)	-	-	100	μA
$I_{CC(stb)}$	standby supply current	ENABLE = LOW (inactive mode)	-	-	1	μA

- [1] Typical values are measured at $T_{amb} = 25\text{ }^{\circ}C$.
- [2] Guaranteed by design and characterization.
- [3] EMI filter line capacitance per data channel from I/O driver to pin; C_{ch} is guaranteed by design.

13. Dynamic characteristics

13.1. Voltage regulator

Table 12. Voltage regulator

$T_{amb} = 25\text{ }^{\circ}C$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Voltage regulator output pin: V_{LDO}						
$t_{startup(reg)}$	regulator start-up time	$V_{CCA} = 1.8\text{ V}$; $V_{SUPPLY} = 3.5\text{ V}$; $C_{ext} = 1\text{ }\mu F$; Fig. 6	-	-	100	μs
$t_{f(o)}$	output fall time	$V_{O(reg)} = 2.9\text{ V to }1.8\text{ V}$; SEL = LOW to HIGH; Fig. 5	-	-	1	ms
$t_{r(o)}$	output rise time	$V_{O(reg)} = 1.8\text{ V to }2.9\text{ V}$; SEL = HIGH to LOW; Fig. 5	-	-	100	μs

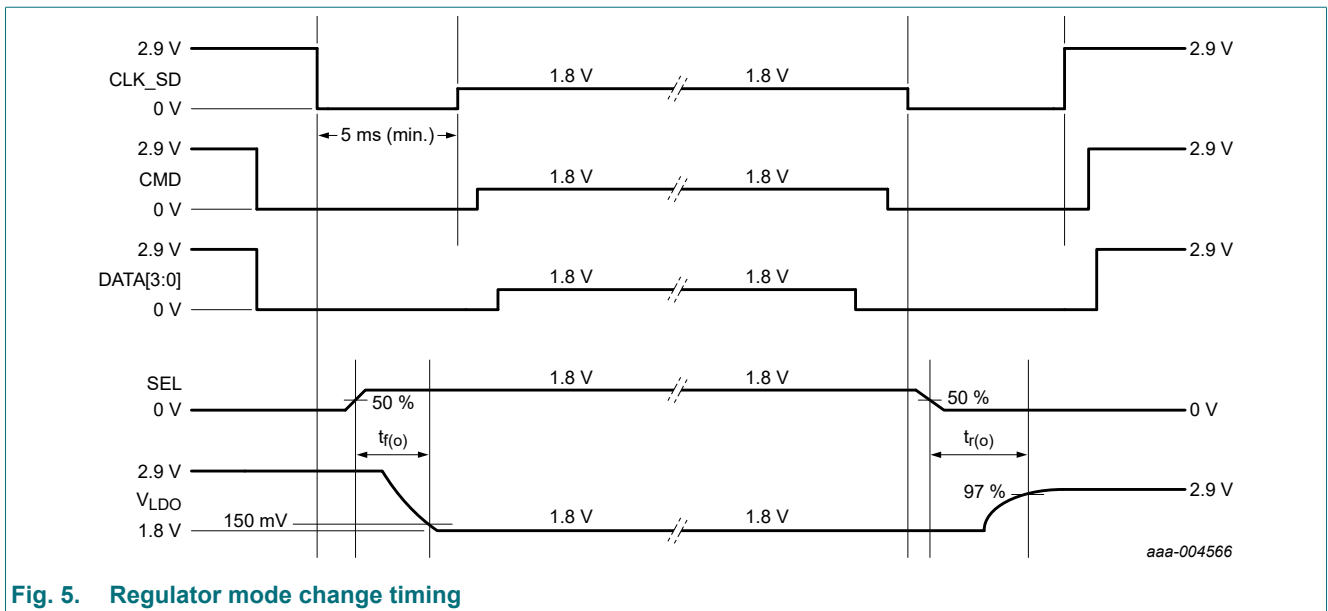
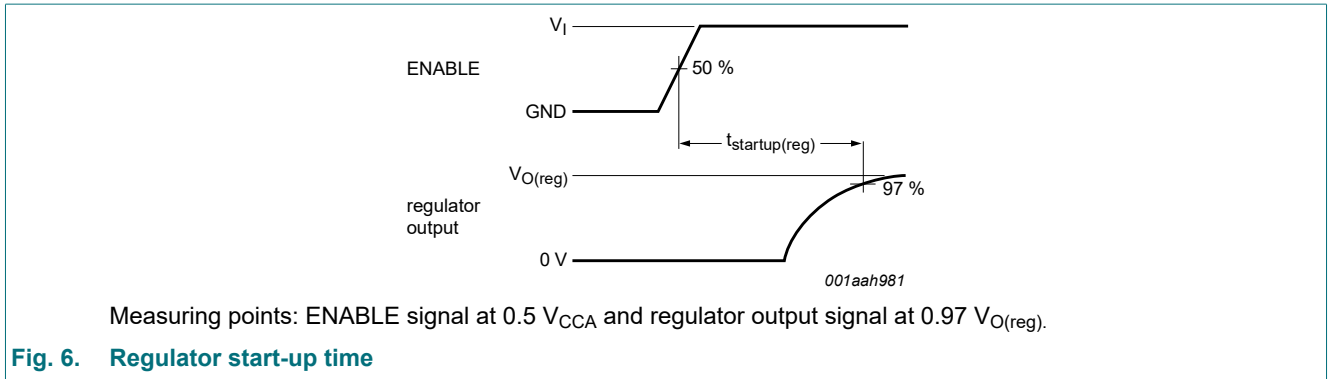


Fig. 5. Regulator mode change timing

SD 3.0-compliant memory card integrated dual level translator with EMI filter and ESD protection



13.2. Level translator

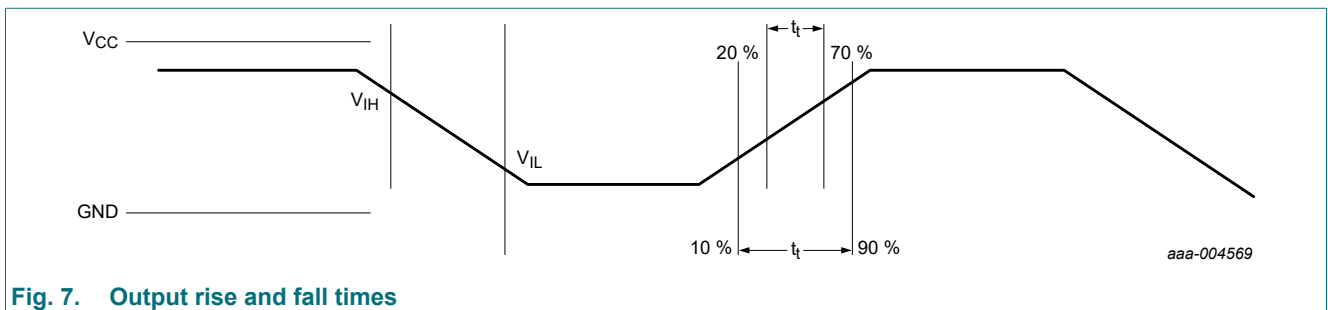
Table 13. Level translator dynamic characteristics

At recommended operating conditions; $V_{CCA} = 1.8\text{ V}$; $T_{amb} = 25\text{ }^\circ\text{C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Host-side transition times						
t_r	rise time	SEL = HIGH (1.8 V interface)	[1]	0.4	1.0	ns
t_f	fall time	SEL = HIGH (1.8 V interface)	[1]	0.4	1.0	ns
Card-side transition times						
t_r	rise time	SEL = HIGH (1.8 V interface)	[2]	0.9	1.4	ns
t_f	fall time	SEL = HIGH (1.8 V interface)	[2]	0.9	1.4	ns
Host-side to card-side propagation delay						
DATAx_H to DATAx_SD, CMD_H to CMD_SD and CLK_IN to CLK_SD						
t_{pd}	propagation delay	SEL = HIGH (1.8 V interface)	-	2.4	3.5	ns
Host-side to host-side propagation delay						
CLK_IN to CLK_FB						
t_{pd}	propagation delay	SEL = HIGH (1.8 V interface)	-	4.8	7.0	ns
Card-side to host-side propagation delay						
DATAx_SD to DATAx_H and CMD_SD to CMD_H						
t_{pd}	propagation delay	SEL = HIGH (1.8 V interface)	-	2.4	3.5	ns

[1] Transition between $V_{OL} = 0.35 \times V_{CCA}$ and $V_{OH} = 0.65 \times V_{CCA}$.

[2] Transition between $V_{OL} = 0.45\text{ V}$ and $V_{OH} = 1.4\text{ V}$.



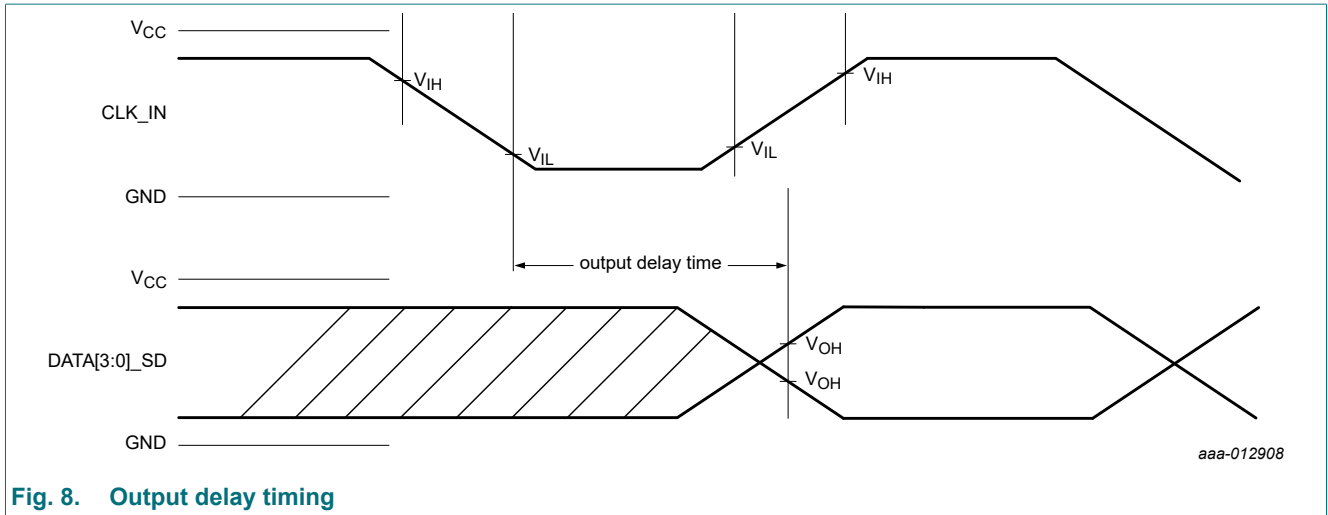


Fig. 8. Output delay timing

13.3. ESD characteristics of pin write protect and card detect

Table 14. ESD characteristics of pin write protect and card detect

At recommended operating conditions; $V_{CCA} = 1.8\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
ESD protection pins: WP and CD						
V_{BR}	breakdown voltage	TLP; $I = 1\text{ mA}$	-	8	-	V
r_{dyn}	dynamic resistance	positive transient	[1]	-	0.5	Ω
		negative transient	[1]	-	0.5	Ω

[1] TLP according to ANSI/ESD STM5.5.1/IEC 62615 $Z_o = 50\ \Omega$; pulse with = 100 ns; rise time = 200 ps; averaging window = 50 ns to 80 ns.

14. Test information

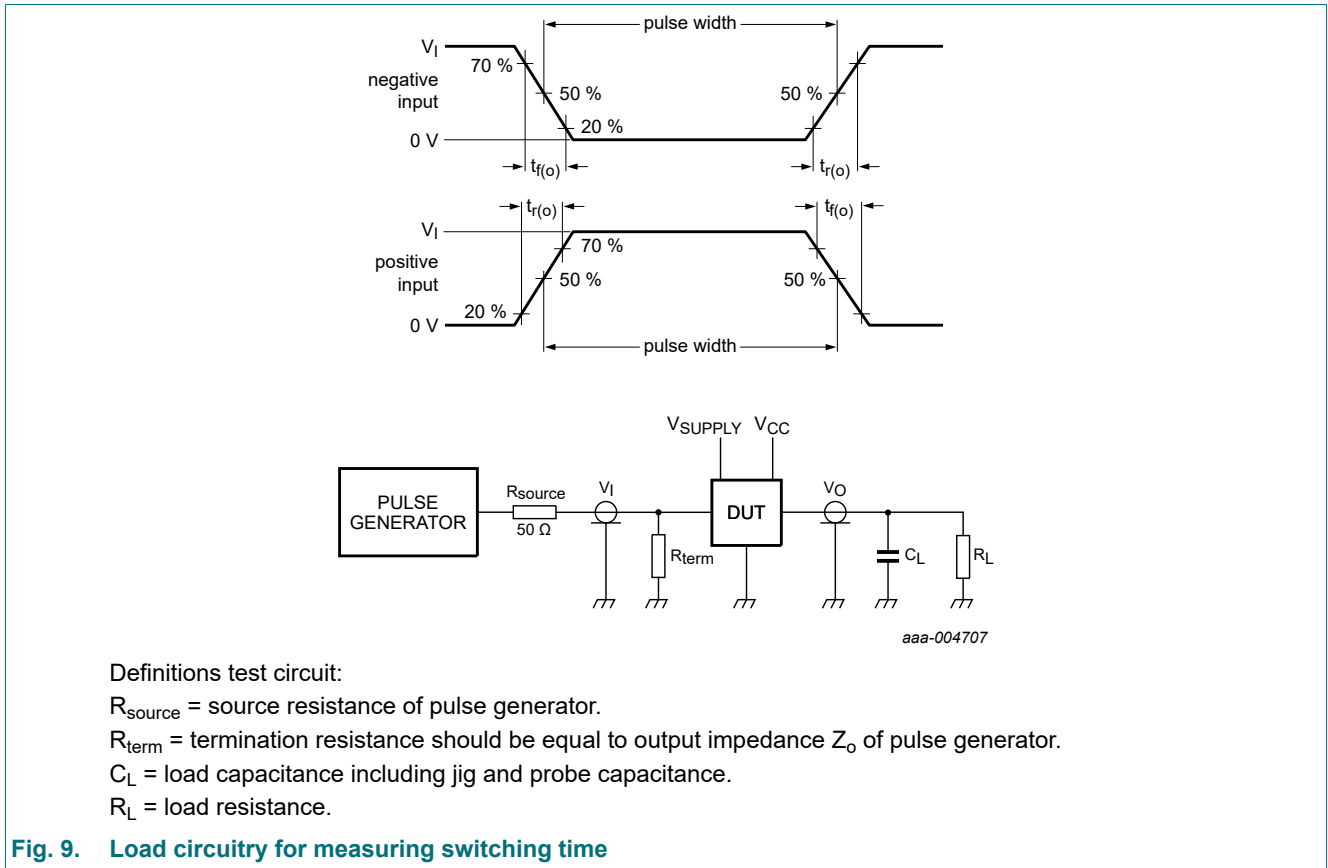


Fig. 9. Load circuitry for measuring switching time

15. Package outline

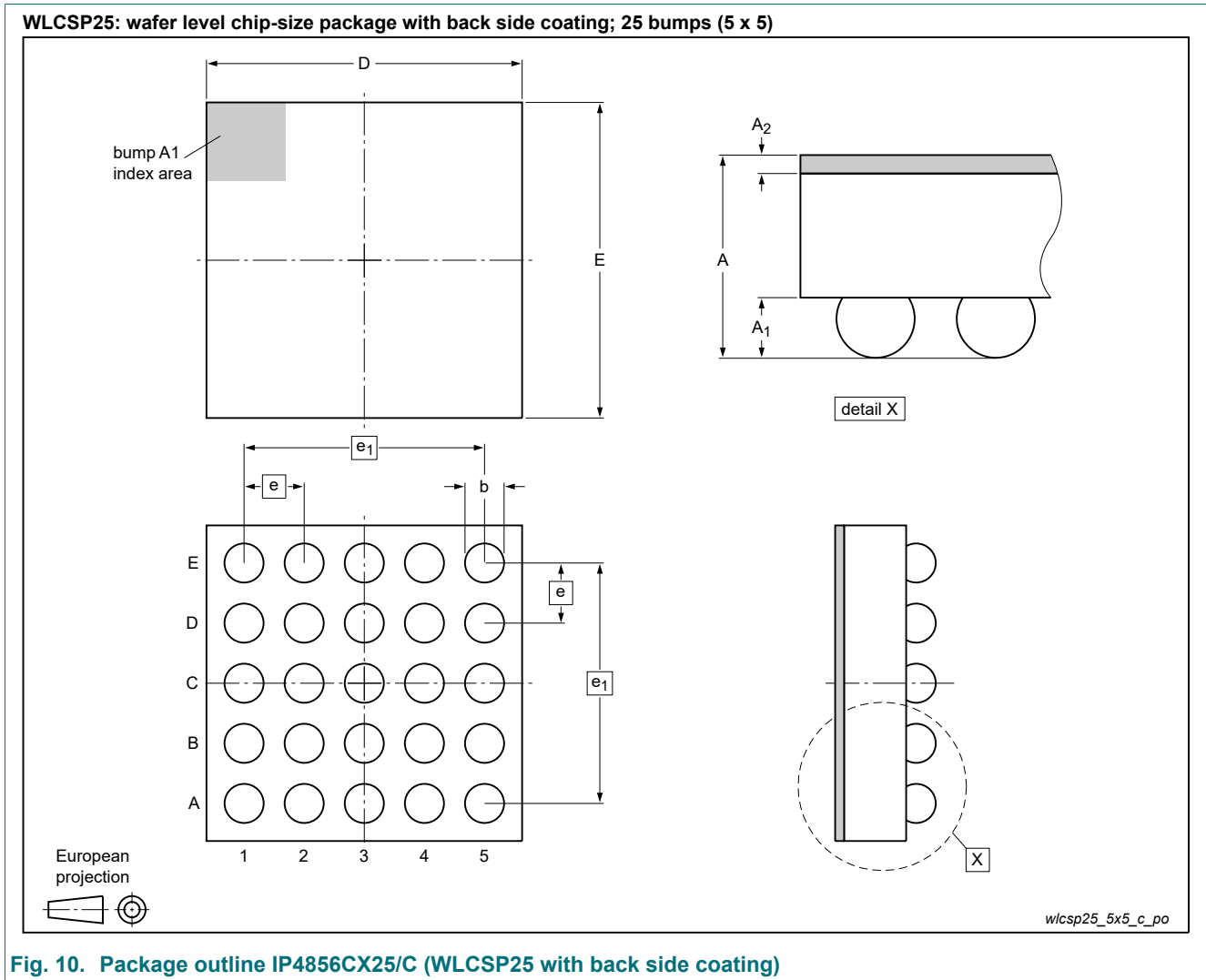


Fig. 10. Package outline IP4856CX25/C (WLCSP25 with back side coating)

Table 15. Dimensions for Figure 9

Symbol	Min	Typ	Max	Unit
A	0.47	0.51	0.55	mm
A ₁	0.18	0.20	0.22	mm
A ₂	0.03	0.04	0.05	mm
b	0.23	0.25	0.27	mm
D	2.01	2.05	2.09	mm
E	2.01	2.05	2.09	mm
e	-	0.4	-	mm
e ₁	-	1.6	-	mm

16. Design and assembly recommendations

16.1. PCB design guidelines

For optimum performance, use a Non-Solder Mask PCB Design (NSMD), also known as a copper-defined design, incorporating laser-drilled micro-vias connecting the ground pads to a buried ground-plane layer. This results in the lowest possible ground inductance and provides the best high frequency and ESD performance. For this case, refer to [Table 16](#) for the recommended PCB design parameters.

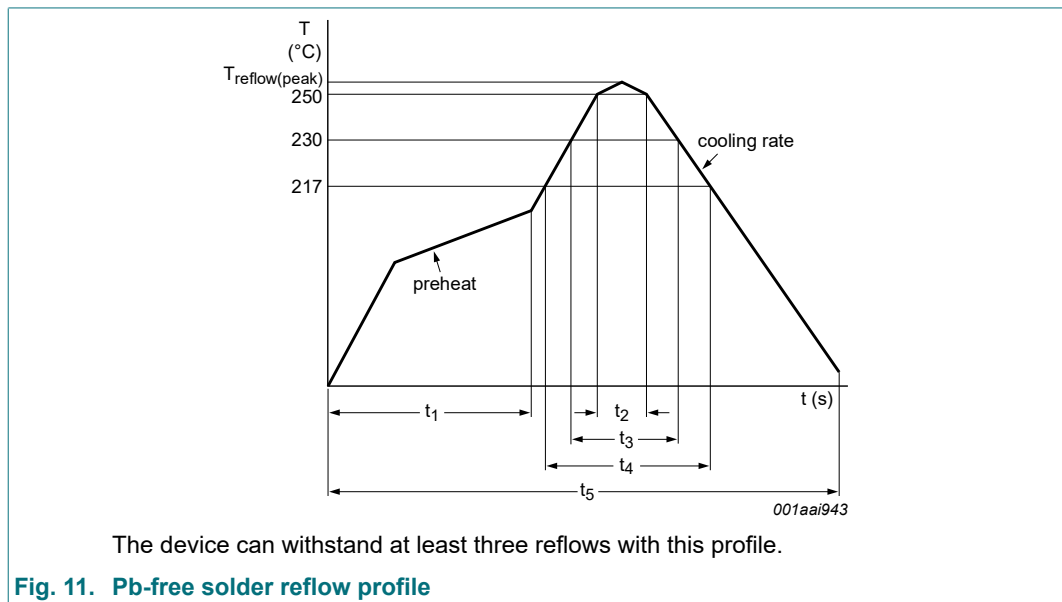
Table 16. Recommended PCB design parameters

Parameter	Value or specification
PCB pad diameter	250 μm
Micro-via diameter	100 μm (0.004 inch)
Solder mask aperture diameter	325 μm
Copper thickness	20 μm to 40 μm
Copper finish	AuNi or OSP
PCB material	FR4

16.2. PCB assembly guidelines for Pb-free soldering

Table 17. Assembly recommendations

Parameter	Value or specification
Solder screen aperture diameter	290 μm
Solder screen thickness	100 μm (0.004 inch)
Solder paste: Pb-free	SnAg (3 % to 4 % Cu (0.5 % to 0.9 %))
Solder to flux ratio	50 : 50
Solder reflow profile	see Fig. 11



SD 3.0-compliant memory card integrated dual level translator with EMI filter and ESD protection

Table 18. Reflow soldering process characteristics

 $T_{amb} = 25\text{ °C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{\text{reflow(peak)}}$	peak reflow temperature		230	-	260	°C
t_1	time 1	soak time	60	-	180	s
t_2	time 2	time during $T \geq 250\text{ °C}$	-	-	30	s
t_3	time 3	time during $T \geq 230\text{ °C}$	10	-	50	s
t_4	time 4	time during $T \geq 217\text{ °C}$	30	-	150	s
t_5	time 5		-	-	540	s
dT/dt	rate of change of temperature	cooling rate	-	-	-6	°C/s
		preheat	2.5	-	4.0	°C/s

17. Abbreviations

Table 19. Abbreviations

Acronym	Description
DUT	Device Under Test
EMI	ElectroMagnetic Interface
ESD	ElectroStatic Discharge
FR4	Flame Retard 4
MMC	MultiMedia Card
NSMD	Non-Solder Mask PCB Design
OSP	Organic Solderability Preservation
PCB	Printed-Circuit Board
RoHS	Restriction of Hazardous Substances
SD	Secure Digital
WLCSP	Wafer-Level Chip-Scale Package

18. Revision history

Table 20. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
IP4856CX25_C v.3	20191213	Product data sheet	-	IP4856CX25_C v.2
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.Legal texts have been adapted to the new company name where appropriate.Added figure "Marking description"			
IP4856CX25_C v.2	20141015	Product data sheet	-	IP4856CX25 v.1
IP4856CX25 v.1	20140602	Preliminary data sheet	-	-

19. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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 Date of release: 13 December 2019

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